Materials

International Symposium on Physics and Device Applications of Two-dimensional Materials











Nanjing University
July 12-15

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AGENDA

DAY 1 Monday, July 13

OPENING CEREMONY

Venue: 1st floor, Zhixing Hall

venue. 1 11001, Zilixilig Hatt		
A.M.	8:45-9:00	Opening Ceremony
	9:00-9:35	Kang L. Wang UCLA, USA
		Topological Insulator and other 2D materials
	9:35-10:10	Hongjun Gao Chinese Academy of Sciences, China
		Construction of 2D Atomic Crystals on Transition Metal
		Surfaces: Graphene, Silicene, Germanene, and Hafnene
	10:10-10:30	Photo shooting and coffee break
	10:30-11:05	Philip Wong Stanford University, USA
		Making Electrical Contacts to Large-Area, CVD Grown 2D
		Layered Materials
	11:05-11:40	Xiaodong Xu University of Washington, USA
		Excitons in 2D Semiconducting Heterostructures
	11:40-12:15	Lianmao Peng Peking Univeresity, China
		Graphene based high performance Hall elements and
		integrated circuits

Session 1

Venue: 1st floor, Zhixing Hall

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P.M.	14:00-14:35	Manish Chhowalla Rutgers University, USA
		Phase Engineered Transition Metal Dichalcogenides as
		Electrodes for Energy and Electronics
	14:35-15:10	Dapeng Yu Peking University, China
		Magnetotransport and Photoelectric Properties of Graphene
		Vertical Structures
	15:10-15:45	Peide Ye Purdue University, USA
		From Black Phosphorus to Phosphorene
	15:45-16:20	Tianling Ren Tsinghua University, China
	15:20-16:55	Xinran Wang Nanjing University, China
		Electron transport and device physics in monolayer MoS ₂

Electron transport and device physics in monolayer MoS₂

16:55-18:00 Poster Session

18:00-20:00 **Banquet**

Session 2

Venue: 2nd floor, Zhixing Hall

P.M. 14:00-14:35 Andrea Ferrari University of Cambridge, UK

14:35-15:10 Feng Wang UC Berkeley, USA

15:10-15:45 **Wang Yao** The University of Hong Kong, HK, China

Novel exciton systems in transition metal dichalcogenides

monolayers and heterobilayers

15:45-16:20 **Ting Yu** Nanyang Technological University, Singapore

Tuning Electronic and Valley Structures of Two-dimensional Semiconductors by Applying Electrical and Magnetic

potentials

15:20-16:55 Anlian Pan Hunan University, China

Bandgap Engineering on Low Dimensional

Semiconductors: from 1D to 2D Structures

16:55-18:00 Poster Session

18:00-20:00 **Banquet**

DAY 2 Tuesday, July 14

Session 1

Venue: 1st floor, Zhixing Hall

A.M. 8:35-9:05 Xiangfeng Duan UCLA, USA

Two-Dimensional Materials, Heterostructures, and Devices

9:05-9:40 **Wanlin Guo** Nanjing University of Aeronautics and

Astronautics, China

Mechanical-electric-magnetic coupling and energy conversion

in two-dimensional materials

9:40-10:15 **Doron Naveh** *Bar Ilan University, Israel*

Spin pumping and mode locked lasers from topological

insulators

10:15-10:30 Coffee break			
10:30-11:05 Zhihong Chen Purdue University, USA			
Graphene Based All Spin Logic			
11:05-11:40 Kazuhito Tsukagoshi NIMS, Japan			
Atomically thin semiconducting channels for future nano-			
electronics			
11:40-12:15 Zhun-Yong Ong Institute of High Performance Computing,			
Singapore			
Theoretical analysis of electron mobility in single-layer MoS ₂			
field-effect transistors			
P.M. 14:00-14:35 Jian-Bin Xu Chinese University of Hong Kong, HK, China			
Investigation on Graphene-like Materials and their Related			
Devices			
14:35-15:10 Han Wang University of Southern California, USA			
Synthesis and Applications of Novel Two-Dimensional			
Nanomaterials			
15:10-15:45 Yang Chai Hong Kong Polytechnic University, HK, China			
Spin pumping and mode locked lasers from topological			
insulators			
15:45-16:05 Coffee break			
16:05-16:40 Ning Wang Hong Kong University of Science and Technology			
HK, China			
Probing the Electronic States and Impurity Effects in			
Graphene and MoS₂ through Quantum Capacitance			
Measurement			
16:40-17:15 Yuanbo Zhang Fudan University, China			
17:15-17:50 Lin He Beijing Normal University, China			
Gauge fields and non-Abelian gauge fields in graphene			
17:50-18:25 Faxian Xiu Fudan University, China			
Spin-valve Effect in NiFe/MoS ₂ /NiFe Junctions			
Session 2			

Venue: 2nd floor, Zhixing Hall

A.M. 8:35-9:05 **Jun Lou** *Rice University, USA*

Hua Zhang Nanyang Technological University, Singapore 9:05-9:40

Synthesis and Applications of Novel Two-Dimensional

Nanomaterials

	9:40-10:15	Hongtao Yuan Stanford University, USA
		Layered Chalcogenides: from Electronic Structure Evolution
		to Spin-Coupled Valley Current
	10:15-10:30	Coffee break
	10:30-11:05	Yunqi Liu Institute of Chemistry, Chinese Academy of
		Sciences, China
		Synthesis of graphene directly on dielectric substrates
	11:05-11:40	Zheng Liu Nanyang Technological University, Singapore
		Development of Some Novel Two-dimensional Crystals and
		their Heterostructures
	11:40-12:15	Guihua Yu University of Texas, Austin, USA
P.M.	14:00-14:35	Qihua Xiong Nanyang Technological University, Singapore
		Charge-Induced Second-Harmonic Generation in Bilayer
		WSe ₂
	14:35-15:10	Linyou Cao North Carolina State University, USA
		Engineering Light-Matter Interactions at Two-dimensional
		TMDC Materials
	15:10-15:45	Zheyu Fang Peking University, China
		Plasmonic Hot Electrons doping of 2D Materials
	15:45-16:05	Coffee break
	16:05-16:40	Xiaobo Yin University of Colorado, USA
		Nonlinear Spectroscopy of Symmetry Breaking 2D
		Semiconductor Atomic Monolayer
	16:40-17:15	Pingheng Tan State Key Laboratory of Superlattices and
		Microstructures,Institute of Semiconductors, Chinese Academy
		of Sciences, China
		Interface coupling in twisted multilayer graphenes probed by
		Raman spectroscopy
	17:15-17:50	Yuerui Lu Australian National University, Australia
	17:50-18:25	Zhenhua Ni Southeast University, China
		Modulation of the properties of two dimensional materials
		through defect engineering

DAY 3 Wednesday, July 15

Session 1

Venue: 1st floor, Zhixing Hall

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A.M.	8:30-9:05	Chongwu Zhou University of Southern California, USA
		TBD
	9:05-9:40	Kaihui Liu Peking University, China
		Optical Spectroscopy of Individual Carbon Nanotubes with
		Defined Atomic Structure
	9:40-10:15	Kaili Jiang Tsinghua University, China
		High throughput imaging techniques for carbon nanotubes
	10:15-10:30	Coffee break
	10:30-11:05	Ke-qin Zhang Soochoow University, Chian
		Static electric force driven self-assembly of hollow graphene
		spheres
	11:05-11:40	Fengqiu Wang Nanjing University, China
		High-performance photodetectors based on planar
		SWNT/graphene hybrid film
	11:40-12:15	Zhipei Sun Aalto University, Finland
		Ultrafast photonics based on two-dimensional layered materials

Session 2

Venue: 2nd floor, Zhixing Hall

venue. 2 11001, 2111/111g Hatt		
A.M.	8:30-9:05	Fengnian Xia Yale University, USA
		Graphene and Beyond for Nanophotonics
	9:05-9:40	Zongfu Yu University of Wisconsin, USA
		Engineering the flow of light in ultra-thin materials for efficient
		and multispectral photodetectors
	9:40-10:15	Yumeng You Southeast University, China
	10:15-10:30	Coffee break
	10:30-11:05	Qiong Ma MIT, USA
		Hot Carriers and Photoresponse in Graphene-based
		Optoelectronic Devices
	11:05-11:40	Peng Zhou Fudan University, China
		Nonvolatile Memory Based on Few-Layer Materials
	11:40-12:15	Jun He National Center for Nanoscience and Technology,
		China

PRACTICAL INFORMATION

Accommodation

Jingli Hotel (晶丽酒店)

Address No.7, West Beijing Road, Gu Lou (南京市鼓楼区北京西路 7 号)

Tel (025)83714270

(025)80848000

Transport

1. From Nanjing Lukou International Airport 55 minutes by taxi (around 130RMB)

2. From Nanjing Railway Station 15 minutes by taxi (around 17 RMB)

3. From Nanjing South Railway Station 30 minutes by taxi (around 25 RMB)

Conference Venue

Zhixing Hall, Nanjing University (Gulou Campus) 南京大学(鼓楼校区)知行楼



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The Collaborative Innovation Center of Advanced Microstructures (CICAM), a close alliance made up of the national laboratories and centers from Nanjing Univ., Fudan Univ., Shanghai Jiao Tong Univ., Zhejiang Univ., Univ. of Science and Technology of China, and the Hefei Institutes of Physical Science, plus the Huawei Technologies, an advanced industry symbol of China, was formally authenticated by the Ministry of Education and the Ministry of Finance of China in 2014 under the 2011 Plan Initiatives. This alliance, led by Nanjing Univ.,is committed to undertaking advanced R&D activities in broad areas of Science and Technology of Microstructures at the crossover of condensed matter physics, materials sciences, information sciences, and energy technologies, focusing on cutting-edge and emergent sciences and technologies of artificial bandgap matters, correlated electron systems, and small quantum systems, among others in the inter-disciplines, while substantial efforts will be devoted to transfer of research findings into relevant applications.

Under the comprehensive supports of the national administrations and R&D funding agencies, the major strategies developed in the CICAM include recruiting high-level and aggressive younger talents, establishing and promoting advanced research infrastructures and capabilities, and spinning-off innovative technologies for next-generations of quantum devices and integrated systems. One of the CICAM's missions is to establish itself as a leading institution of international reputations in the field of advanced microstructures where research findings and inventions catalyze Chinese industry and meet their core technology needs. The center is also committed to training researchers and drawing prominent scientists from across the country to feed Chinese dreams that rejuvenate the country through science and technology.